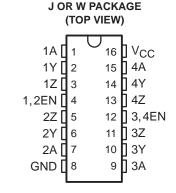
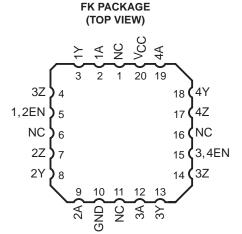
- Meets EIA Standard RS-485
- Designed for High-Speed Multipoint Transmission on Long Bus Lines in Noisy Environments
- Supports Data Rates up to and Exceeding Ten Million Transfers Per Second
- Common-Mode Output Voltage Range of –7 V to 12 V
- Positive- and Negative-Current Limiting
- Low Power Consumption . . . 1.5 mA Max (Output Disabled)

description

The SN55LBC174 is composed of monolithic quadruple differential line drivers with 3-state outputs. This device is designed to meet the requirements of the Electronics Association (EIA) Standard RS-485 and is balanced multipoint optimized for transmission at data rates up to and exceeding 10 million bits per second. Each driver features wide positive and negative common-mode output voltage ranges. current limiting, thermal-shutdown protection making it suitable for party-line applications in noisy environments. This device is designed using LinBiCMOS™, facilitating ultra-low power consumption and inherent robustness.





NC - No internal connection

The SN55LBC174 provides positive and negative-current limiting and thermal shutdown for protection from line fault conditions on the transmission bus line. This device offers optimum performance when used with the SN55LBC173 quadruple line receiver. The SN55LBC174 is available in the 16-pin CDIP package (J), the 16-pin CPAK (W), or the 20-pin LCCC package (FK).

The SN55LBC174 is characterized for operation over the military temperature range of -55°C to 125°C.

FUNCTION TABLE (each driver)

INPUT	ENABLE	OUTPUTS			
INPUT	INFOI ENABLE	Υ	Z		
Н	Н	Н	L		
L	Н	L	Н		
X	L	Z	Z		

H = high level, L = low level, X = irrelevant, Z = high impedance (off)



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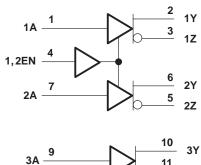
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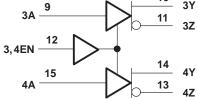
logic symbol†

1,2EN EN \triangleright 2 1Y 3 1Z ∇ 6 2Y 5 2Z 3,4EN EN \triangleright 10 3Y 11 ∇ 3**Z** 14 4Y 15 13

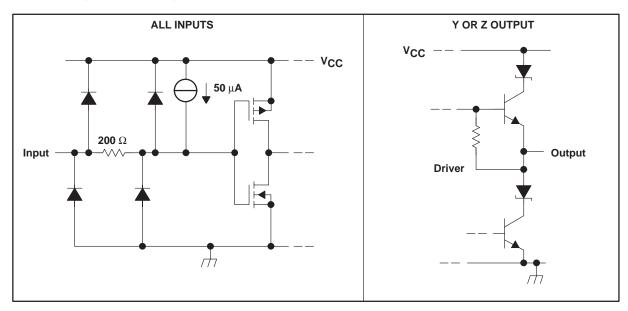
† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for the J or W package.

logic diagram (positive logic)





schematic of inputs and outputs



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absolute maximum ratings over operating free-air temperature (unless otherwise noted)†

Supply voltage range, V _{CC} (see Note 1)	0.3 V to 7 V
Output voltage range, VO	
Input voltage range, V _I	0.3 V to 7 V
Continuous power dissipation	internally limited [‡]
Operating free-air temperature range, T _A	
Storage temperature range, T _{Stq}	
Lead temperature 1.6 mm (1/16 inch) from case for 10 seconds	-65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

DISSIPATION RATING TABLE

PACKAGE	$T_A \le 25^{\circ}C$ POWER RATING	DERATING FACTOR ABOVE T _A = 25°C	T _A = 125°C POWER RATING
FK	1375 mW	11.0 mW/°C	275 mW
J	1375 mW	11.0 mW/°C	275 mW
W	1000 mW	8.0 mW/°C	200 mW

recommended operating conditions

			MIN	NOM	MAX	UNIT
Supply voltage, V _{CC}			4.75	5	5.25	V
High-level input voltage, VIH		2			V	
Low-level input voltage, V _{IL}				0.8	V	
Voltage at any bus terminal (separately or common mode), VO	Y or Z				12	V
				-7	_	
High-level output current, IOH	Y or Z				-60	mA
Low-level output current, IOL	Y or Z				60	mA
Operating free-air temperature, T _A		-55		125	°C	



[‡] The maximum operating junction temperature is internally limited. Use the dissipation rating table to operate below this temperature. NOTE 1: All voltage values are with respect to GND.

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electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST	CONDITIONS	MIN	TYP [†]	MAX	UNIT
VIK	Input clamp voltage	$I_{I} = -18 \text{ mA}$				-1.5	V
11/05/	Differential autout valteur T	$R_L = 54 \Omega$,	See Figure 1	1.1	1.8	5	V
IVODI	Differential output voltage [‡]	$R_L = 60 \Omega$,	See Figure 2	1.1	1.7	5	V
Δ V _{OD}	Change in magnitude of differential output voltage§					±0.2	V
Voc	Common-mode output voltage	$R_L = 54 \Omega$,	See Figure 1			3 -1	٧
Δ VOC	Change in magnitude of common-mode output voltage§]				±0.2	V
IO	Output current with power off	$V_{CC} = 0$,	$V_0 = -7 \text{ V to } 12 \text{ V}$			±100	μΑ
I _{OZ}	High-impedance-state output current	$V_0 = -7 \text{ V to } 12 \text{ V}$				±100	μΑ
lН	High-level input current	V _I = 2.4 V				-100	μΑ
I _I L	Low-level input current	V _I = 0.4 V				-100	μΑ
los	Short-circuit output current	$V_O = -7 V tc$	12 V			±250	mA
IO Output current with power off IOZ High-impedance-state output current IIH High-level input current IIL Low-level input current	No load	Outputs enabled			7	mA	
licc	Supply current (an univers)	INO IOAU	Outputs disabled			1.5	IIIA

[†] All typical values are at $V_{CC} = 5 \text{ V}$ and $T_A = 25^{\circ}\text{C}$.

switching characteristics, V_{CC} = 5 V

	PARAMETER	TEST CO	NDITIONS	TA	MIN	TYP	MAX	UNIT
^t d(OD)	Differential output delay time	$R_1 = 54 \Omega$	See Figure 3	25°C	2	11	20	ns
				−55°C to 125°C	2		40	
4	Differential output transition time	$R_1 = 54 \Omega$	See Figure 3	25°C	4	15	25	ns ns
t _t (OD)	Differential output transition time	N_ = 34 22, See Figure 3 -5	−55°C to 125°C	4		40	115	
	Output enable time to high level	$R_{\rm I} = 110 \Omega$	See Figure 4	25°C			30	ns
^t PZH	Output enable time to night level	KL = 110 52,		−55°C to 125°C			40	
	Output enable time to low level	$R_{\rm I} = 110 \Omega$	See Figure 5	25°C			30	
^t PZL	Output enable time to low level	KL = 110 52,	See Figure 5	-55°C to 125°C			40	ns
+	Output disable time from high level	start finable fine from bigh lovel	25°C			50	no	
^t PHZ	Output disable time from high level	$R_L = 110 \Omega$	See Figure 4	-55°C to 125°C			90	ns
to. 7	Output disable time from low level	R _L = 110 Ω,	See Figure 5	25°C			30	ns
^t PLZ	Output disable time nom low level	110 22,	See Figure 5	−55°C to 125°C			45	115

[‡] The minimum V_{OD} specification does not fully comply with EIA Standard RS-485 at operating temperatures below 0°C. The lower output signal should be used to determine the maximum signal transmission distance.

^{§ ∆|}V_{OD}| and ∆|V_{OC}| are the changes in magnitude of V_{OD} and V_{OC}, respectively, that occur when the input is changed from a high level to a low level.

PARAMETER MEASUREMENT INFORMATION

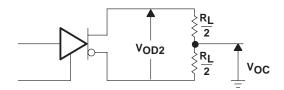


Figure 1. Differential and Common-Mode Output Voltages

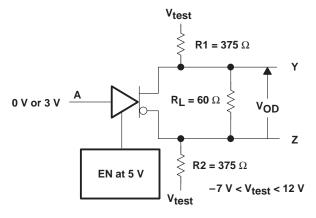
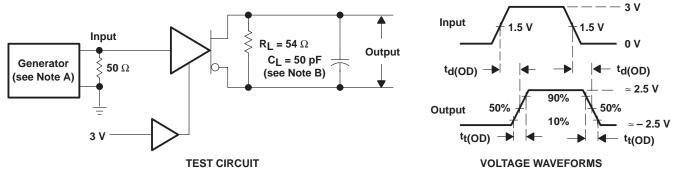


Figure 2. Driver $V_{\mbox{\scriptsize OD}}$ Test Circuit

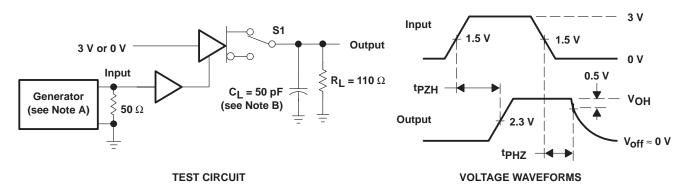


NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR \leq 1 MHz, duty cycle \leq 50%, $t_{\Gamma} \leq$ 5 ns, $t_{\Gamma} \leq$ 6 ns, $t_{\Gamma} \leq$ 6 ns, $t_{\Gamma} \leq$ 7 ns, $t_{\Gamma} \leq$ 7 ns, $t_{\Gamma} \leq$ 7 ns, $t_{\Gamma} \leq$ 7 ns, $t_{\Gamma} \leq$ 8 ns, $t_{\Gamma} \leq$ 9 ns,

B. CL includes probe and stray capacitance.

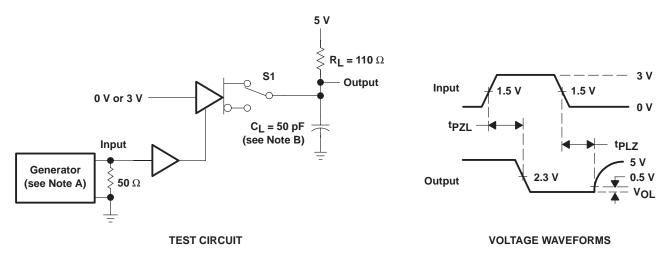
Figure 3. Driver Differential-Output Test Circuit Delay and Transition-Time Waveforms

PARAMETER MEASUREMENT INFORMATION



- NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR \leq 1 MHz, duty cycle \leq 50%, $t_{\Gamma} \leq$ 5 ns, $t_{f} \leq$ 5 ns, $t_{O} =$ 50 Ω .
 - B. C_L includes probe and stray capacitance.

Figure 4. t_{PZH} and t_{PHZ} Test Circuit and Waveforms

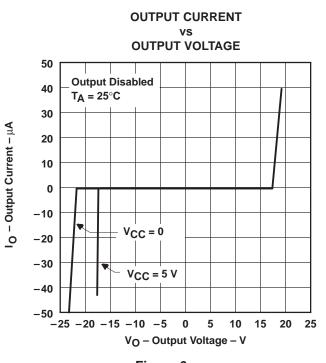


- NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR \leq 1 MHz, duty cycle \leq 50%, $t_{f} \leq$ 5 ns, $z_{O} =$ 50 Ω .
 - B. C_L includes probe and stray capacitance.

Figure 5. tpzL and tpLZ Test Circuit and Waveforms

TYPICAL CHARACTERISTICS

VOL - Low-Level Output Voltage - V



LOW-LEVEL OUTPUT VOLTAGE
vs
LOW-LEVEL OUTPUT CURRENT

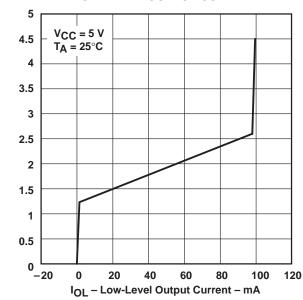
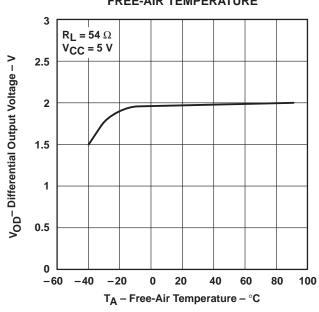


Figure 6

Figure 7





HIGH-LEVEL OUTPUT VOLTAGE
VS

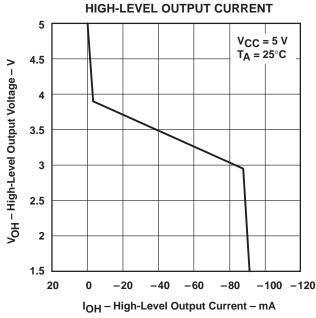


Figure 8

TYPICAL CHARACTERISTICS

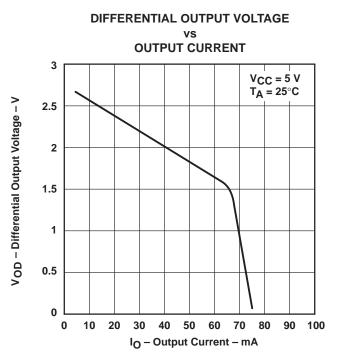


Figure 10

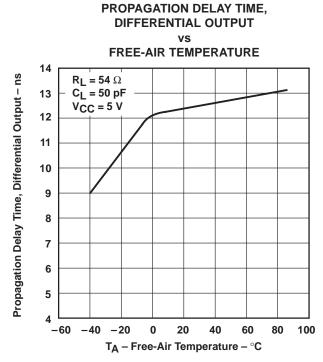


Figure 11

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